

FDMS86101DC

Data Sheet

Trans MOSFET N-CH 100V 14.5A 8-Pin Power 56 T/R

Manufacturers ON Semiconductor, LLC

Package/Case Power 56

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

Please submit RFQ for FDMS86101DC or Email to us: sales@ovaga.com We will contact you in 12 hours.



General Description

This N-Channel MOSFET is produced using an advanced PowerTrench® process that incorporates Shielded Gate technology. Advancements in both silicon and Dual CoolTM package technologies have been combined to offer the lowest rDS(on) while maintaining excellent switching performance by extremely low Junction-to-Ambient thermal resistance.

Application

ONSEMI



Related Products



FDC645N ON Semiconductor, LLC SSOT-6



ON Semiconductor, LLC SSOT-6

FDC637BNZ



FDC6305N ON Semiconductor, LLC SSOT-6



FDD8647L
ON Semiconductor, LLC
TO-252-3



FDD5N50NZTM
ON Semiconductor, LLC
TO-252



FDC602P ON Semiconductor, LLC SOT163



FDB070AN06A0

ON Semiconductor, LLC
TO-263



FDD3670 ON Semiconductor, LLC TO-252AA